

Naphthalenediimide-Based Copolymers Incorporating Vinyl-Linkages for High-Performance Ambipolar Field-Effect Transistors and Complementary-Like Inverters under Air

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On page 3593, Table 2, for the *p*-channel mobilities of TGBC FETs, the standard deviations of the NVT-8 and PVT-10 based FETs were reported incorrectly. The right values should be ± 0.03 . For TGBC FETs based on P(NDI2OD-T2), PMMA with a weight-average molecular weight of 120 kDa was used as a gate dielectric. However, for TGBC FETs based on PNVT-8 or PNVT-10, PMMA with a weight-average molecular weight of 996 kDa was used as a gate dielectric. The corrected Table 2 is shown here.

Table 2. Performance Parameters of the FET Devices Based on Three NDI-Based Polymers with Different Devices Configurations

polymer	<i>n</i> -channel			<i>p</i> -channel		
	$\mu_{e,avg}$ [$\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$]	$\mu_{e,max}$ [$\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$]	I_{on}/I_{off}	$\mu_{h,avg}$ [$\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$]	$\mu_{h,max}$ [$\text{cm}^2 \text{V}^{-1} \text{s}^{-1}$]	I_{on}/I_{off}
P(NDI2OD-T2) ^a	0.18 (± 0.01)	0.19	$>1 \times 10^5$	NA	NA	NA
PNVT-8 ^a	0.70 (± 0.05)	0.78	$>1 \times 10^3$	0.12 (± 0.02)	0.15	>50
PNVT-10 ^a	0.50 (± 0.02)	0.55	>500	0.10 (± 0.01)	0.12	>50
P(NDI2OD-T2) ^b	0.23 (± 0.03)	0.27	$>1 \times 10^5$	NA	NA	NA
PNVT-8 ^b	1.10 (± 0.25)	1.4	>1500	0.03 ($\pm 5 \times 10^{-3}$)	0.04	>550
PNVT-10 ^b	0.95 (± 0.15)	1.13	>400	0.02 ($\pm 4 \times 10^{-3}$)	0.04	>55
P(NDI2OD-T2) ^c	0.30 (± 0.05)	0.40	$>1 \times 10^5$	NA	NA	NA
PNVT-8 ^d	1.05 (± 0.05)	1.13	$>1 \times 10^4$	0.15 (± 0.03)	0.23	$>1 \times 10^4$
PNVT-10 ^d	1.10 (± 0.15)	1.57	$>1 \times 10^4$	0.18 (± 0.03)	0.30	$>1 \times 10^4$

^aBGBC FETs without PFBT modification, measured in glovebox. ^bBGBC FETs with PFBT modification, measured in glovebox. ^cTGBC FETs using the PMMA dielectric with a weight-average molecular weight of 120 kDa were measured in ambient. ^dTGBC FETs using the PMMA dielectric with a weight-average molecular weight of 996 kDa were measured in ambient.